Low Frequency Quantum Transport in a Three-probe M esoscopic Conductor

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The low frequency quantum transport properties of a three-probe m esoscopic conductor are studied using Buttiker's AC transport form alism. The static transm ission coe cients and em ittance m atrix of the system were com puted by explicitly evaluating the various partial density of states (PDOS). We have investigated the nite size e ect of the scattering volum e on the global PDOS. By increasing the scattering volum e we observed a gradual in provement in the agreement of the total DOS as computed externally or locally. Our num erical data permits a particular tting form of the nite size e ect.

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1 Introduction

In recent years extensive investigations of ballistic and m esoscopic quantum conductors have been carried out[1]. Experim entally the advances in nanotechnology have enabled the possibility of fabricating submicron structures with linear size of 1000 Angstrom or less. Due to quantum size e ect, the transport properties of these small systems can be very dierent from their classical counterpart and m any interesting phenom ena have been discovered [1]. On the theoretical side, a m ain tool for understanding static ballistic transport is based on the scattering approach of Landauer-Buttiker form alism [2, 3].

It has been realized that the usual static scattering approach can not be directly applied to dynam ic transport problem swhere the external potential has a tim e dependent oscillating component. A s shown by Buttiker and his co-workers, a direct application of the original approach of Landauer-Buttiker form alism can not yield electric current and charge conservation. To preserve this conservation, it is necessary to consider the implication of the long range C oulom b interaction. A s a result the AC transport theory for coherent quantum conductors are more complicated. At present there are several approaches to deal with the problem of computing AC conductance. In a strongly correlated electronic system, the Anderson impurity model is offen used. To treat AC transport one employs the linear response theory in conjunction with the K eldysh G reen's function which is offen applied to deal with non-equilibrium problem s[4]. O ne can also use K ubo's linear response theory by assuming that the electric eld inside the sample is known a priori. H owever this is a very strong requirement[5].

A long another line of developm ent B uttiker and his co-workers have advanced a current conserving form alism [6]. The key idea in this theory is to consider the self-consistent internal potential so that the current and the charge is conserved. In a series of articles, B uttiker and co-workers investigated several low frequency quantum transport problem s[6, 7, 8, 9, 10, 11]. To rst order in frequency !, the response of an arbitrary scattering problem to quasi-static perturbations in the scattering potential is naturally expressed in term s of a set of local partial density of states (PDOS) each associated with one elem ent of the scattering m atrix. This AC transport form alism has also been extended to second order in frequency ! in the quantum hall regim e[11].

The application of Buttiker's AC transport theory is easier in 1D, such as a 1D quantum well, a -function potential, and a perfect quantum wire, where the scattering matrix and wave function can be obtained analytically. Much intuition and interesting results have been obtained from 1D calculations which can often been done analytically. The investigations for 2D conductors have recently begun [12, 13, 14, 15] and the dynam ic transport response of a 3D atom ic wire has been calculated using rst principles [16]. However, due to technical di culties, in 2D one usually can not obtain analytical expressions for the AC adm ittance except for very special cases [13, 14]. For more general situations num erical calculations are needed.

It is the purpose of this article to further investigate AC adm ittance of 2D coherent conductors in the ballistic regime. In particular we shall focus on num erically analyzing a three probe conductor as shown in Figure (1). There are several m otivations for this study. First, sim ilar to that of the DC transport situation [1], we believe coherent AC adm ittance of multiprobe (by multiprobe we mean more than two probes) conductors should be studied in detail since usually experim entalm easurem ents are conducted in multiprobe setups. How ever to the best of our know ledge there is as yet a detailed num erical analysis of any 2D multi-probe system s. Second, in our investigations of two-probe conductors [12, 13], an important technical point is the size e ect of the scattering volum e. It was found [18, 12, 13] that the total PDOS as computed from external global PDOS (GPDOS) does not equal to that com puted from the localPDOS (LPDOS), unless the scattering volume is very large. This led to a violation of the current conservation and gauge invariance in num erical calculations where the scattering volum e is always nite. Hence there is a need to explicitly and system atically exam ine the scattering volum e size e ect. Finally, in order to study certain physical e ects such as the inelastic and dissipative e ects using the quantum scattering approach, a very useful phenom enological approach is to introduce ctitious links from the conductor to external dissipative reservoirs [17]. In this case one must deal with multi-probe situations.

To these purposes we have com puted the low frequency adm ittance of a threeprobe junction (see Fig. (1)). We have exam ined the em ittance matrix for both the tunneling regime and the transmissive regime in detail. The behavior of the em ittance matrix is found to be closely related to that of the transmission coe – cients. We have computed the total PDOS from both the external GPDOS and the local PDOS, and largely speaking the two total PDOS as obtained approach each other as the scattering volume is increased. We found that there exists a \critical region" in energy near the second propagating subband threshold, such that within this region the charge conservation is not strictly obeyed for any – nite scattering volume. How ever the larger the scattering volume, the sm aller the \critical region" is.

This paper is organized as the following. In the next section we set out the theoretical and numerical procedures of computing the transmission functions. In section III we present and analyze the numerical results. Both the dynamic and static transport properties and their relationship will be discussed. Finally, a summary is given in section IV.

2 Theoretical and num erical analysis

The current conserving dynam ic transport form alism proposed by Buttiker and co-workers is amply reviewed in several articles [19] and we refer interested readers to them. In this section we shall only outline our theoretical and num erical procedures to compute the necessary quantities such as the various partial density of states for the 3-probe system.

It has been shown by Buttiker, Thom as, Prêtre, Gasparian and Christen β , 6, 7, 18], to linear order in frequency ! the adm ittance is given by the following formula,

$$g^{I}$$
 (!) = g^{e} (! = 0) $i! e^{2}E$ (1)

where the emittance matrix E is calculated from the various partial density of states:

$$E = \frac{dN}{dE} \quad D \qquad : \qquad (2)$$

The subscripts indicates scattering from a lead labeled by to that labeled by . The rst term in the em ittance matrix gives the AC response of the system to the external potential change, while the second term is from the internal potential change induced by the external perturbations. The external contribution is determined by the global partial density of states[9]: for a large scattering volume the global PDOS can be expressed in terms of the energy derivative of the scattering matrix elements[20]

$$\frac{dN}{dE} = \frac{1}{4} \overset{0}{i} s^{y} \frac{ds}{dE} \qquad \frac{ds^{y}}{dE} s^{A} : \qquad (3)$$

On the other hand the internal contribution D is related to the local PDOS, and within the Thom as Ferm i linear screening model is given by

D
$$dr \frac{dn(;r)}{dE} \frac{dn(r)}{dE} \frac{dn(r)}{dE} \frac{dn(r;)}{dE} \frac{dn(r;)}{d$$

where the local PDOS (called in jectivity) is calculable from the scattering wavefunction,

$$\frac{dn(r;)}{dE} = \frac{1}{hJ}j(r)j^{2};$$
(5)

where J is the incident ux and (r) is the scattering wavefunction for electrons coming from the probe . In the absence of a magnetic eld, the emissivity dn(;r)=dE equals to the injectivity [11]. Finally, dn(r)=dE = P^{P} dn(;r)=dE is the total local density of states. It is straightforward to prove that the current is conserved since the admittance matrix g^{I} satisfies P^{I} g^{I} (!) = 0. This can be seen by realizing that P^{P} dN =dE dN =dE is the injectance which is identical to P^{P} D.

To compute the various PDOS, for simplicity we shall focus on the rst transport subband only, thus the incom ing electron energy is restricted to within the interval $(=a)^2 < E < (2 = a)^2$ in units of $h^2 = (2m a^2)$ with m the electric mass of the electron and a the width of the leads (see Fig. (1)). Multi-subbands can also be included without di culties, such as that of Ref. [16]. The scattering properties of the three-probe system is then characterized by a 3 3 scattering fs q w ith = 1;2;3. For example, for an incident electron matrix S(E) com ing from probe 1, it scatters in the scattering volum e, and then re ects back to probe 1 with a probability amplitude given by $\dot{\mathbf{p}}_{11}$ or transmits to probes 2 and 3 with probability amplitudes $j_{21}j_{11}$ and $j_{31}j_{11}$ respectively. The transmission coe cients can thus be expressed in term s of scattering m atrix, i.e. T = †s f. For the system of qure (1), the scattering matrix has the following symmetry: $\dot{p}_{11} = \dot{p}_{22} \dot{j} \dot{p}_{21} j = \dot{p}_{12} \dot{j} \dot{p}_{31} j = \dot{p}_{32} \dot{j} \dot{p}_{13} j = \dot{p}_{23} j and \dot{p}_{13} j = \dot{p}_{31} j$. Therefore, there are only four distinct elements out of nine.

For the three-probe conductor of Figure (1), the quantum scattering problem is solved using a mode matching method. The wavefunction in region I can be written as

$$I = \sum_{n=1}^{X} (y) (a_n e^{ik_n x} + b_n e^{-ik_n x});$$
(6)

where $_{n}(y)$ is the transverse wave function, $k_{n}^{2} = E$ $(n = a)^{2}$ is the transport energy, a_{n} is the input parameter, and b_{n} is the rejection amplitude. Similarly for region II, we have

$$_{II} = \sum_{n}^{X} (y) (c_{n} e^{ik_{n}x} + d_{n} e^{-ik_{n}x}) :$$
 (7)

For region III,

$$III = \int_{n}^{X} (x) (e_n e^{ik_n y} + f_n e^{-ik_n y});$$
(8)

where c_n and e_n are transmission amplitudes and d_n and f_n are input parameters. The wavefunction in region IV is the combination of wavefunctions in regions I, II, and III. At the boundaries of the various regions, we match the wavefunctions and their derivatives and this leads to the desired transmission coecients with which the scattering wave functions Eqs. (6)-(8) are also determined.

If we choose point 0 as the origin (see gure 1), the scattering matrix $s_1\,$ is dened as

$$s_{11} = b_1$$

 $s_{12} = c_1 e^{ik_1 a}$
 $s_{13} = e_1 e^{ik_1 a}$: (9)

U sing Eqs. (2)–(5) and the solution of the scattering problem , we can explicitly compute the low frequency admittance.

3 Results

We have investigated the transm ission coe cient and the emittance matrix in two di erent transport regimes for various system parameters. The nst regime is very transm issive and the second is a tunneling regime where tunnel barriers are added at the probes. The AC response of these regimes can be quite di erent as a transm issive situation tends to be inductive, while a non-transm issive case tends to be capacitive (see below). The low frequency admittance is given by Eq. (1) in which the DC conductance g^e (! = 0) of our three-probe system is determined using transm ission coe cients by applying the Buttiker multi-probe conductance form ula [3].

3.1 Emittance

In Figure (2) we show the transmission coe cients and the emittance E in the transmissive regime as a function of the incoming electron energy. In this case the system does not show any resonance behavior and the transmission coe cients T (E) are quite large form ost of the energy range while the rejection coe cient R_{11} is small (Fig. (2a)). It is interesting to not that the shape of emittance are similar to that of the corresponding transmission coe cients, as shown in Fig. (2b). This is different from cases where quantum resonances dominant the transport[12] (see below) and for that case the AC responses follow the DC transmissions only at the resonances.

There are two di erent responses to the external time varying potential: capacitive and inductive depending on the sign of the emittance matrix element E_{11} . A coording to Eq.(2), E_{11} consists of two terms: $dN_{11}=dE$ the capacitive term and D_{11} the inductive term. For a two probe capacitor there is no DC current so that $dN_{12}=dE = 0$. As a result E_{12} is negative. Therefore for a capacitor $E_{11} = E_{12}$ is positive. Extending this notion, one concludes that the system responds capacitively if E_{11} is positive. For a ballistic conductor with complete transmission $dN_{11}=dE$ vanishes and E_{11} is negative. In other words, negative E_{11} gives an inductive response. These di erent responses are clearly shown in Fig. (2).

The AC transport properties are very di erent in the tunneling regime. To establish such a regime, we have put tunneling barriers inside probes 1 and 2 at the junctions between the probes and the scattering volume. In particular the barrier heights are $V_{\text{barrier}} = 40E_1$, and the width is 0:1 where the width of the wire a has been set to one. No barrier is added in probe 3. We have also included a potential well with depth $V_{well} = 40E_1$ in the center of the scattering volume with a size of 2:8 1:9. The well and barriers establish several transport resonances, these are clearly marked by the sharp peaks in the electron dwell time de ned as [21]

$$= \frac{1}{J} \int_{J}^{Z} j (r) \int_{J}^{2} d^{3}r ; \qquad (10)$$

where is the scattering volum e. $_1$ is plotted against energy in Fig. (3) while the inset shows $_3$. The dwell tim e m easures the duration an electron spends in the scattering volum e. Thus if transport is mediated by resonance states we expect much longer dwell times [2] at the resonances. This idea has recently been proved by Iannaconne [23]. Fig. (3) shows that three resonance states, with energies $E_1 = 132$, $E_2 = 24.1$ and $E_3 = 35.6$ are established. The quantum resonances also leads to sharp peaks in the transmission coe cient T $_{21}$ and rejection coe cient R $_{11}$, as shown by the solid lines of Fig. (4a,4b). At these resonances both the GPDOS and LPDOS take maximum values, leading to the sharp jumps in the emittance E_{11} and E_{21} as shown by the data points in Fig. (4a,4b). The variations of E_{11} and E_{21} as functions of energy E are very closely correlated with those of R $_{11}$ (E) and T $_{21}$ (E) near the resonance transmission to that probe is not as sharp, and the transport behavior shows a mixture of tunneling and transmissive nature, as shown in Fig. (4c).

In the tunneling regime the AC response changes sharply from inductive at

one side of the resonance energy to capacitive on the other side of the resonance or vise versa, in distinctive di erence as com pared to the transmissive case discussed above. Let's exam ine E_{11} near resonance E_3 . As the energy approaches to E_3 , the system ist responds inductively and is followed by a strong capacitive response. This behavior is clearly related to the fact that the resonance is characterized by a complete re ection indicated by the large peak in the re ection coe cient (see Fig. (4a)). This behavior has been seen previously in 2D quantum wires[13]. On the other hand, for 1D resonance tunneling, a Breit-W igner type transmission resonance gives rise to the sim ilar AC response behavior [7] discussed here. W hen the incident energy is near the resonance E_1 , the AC response is reversed: rst capacitively and then inductively. Hence the behavior near E_1 and E_3 are very di erent. For energy near E_1 the emittance behaves like an odd function but near E_3 it is like an even function. The reason, as we have checked num erically, is that the external and the internal responses do (not) reach the maximum at the same energy for E near E_3 (E₁). This behavior of E_{11} is also a manifestation of the rejection coe cient R $_{11}$. As energy sweeps through E $_1$, the strong capacitive AC response is due to the complete re ection peak, and the following inductive response is because the rejection coe cient R₁₁ 0. Hence in the AC response of a system, near a quantum resonance whether it is voltage following current (capacitive) rst, or current following voltage (inductive) rst, can only be determ ined by detailed analysis and the outcom e depends on the peculiarities of the system such as the existence of a third probe as we have studied here. In Figure (4c) we show the emittance matrix elements E_{13} . Although they have much smaller values they do exhibit dips around three resonant energies E_1, E_2 , and E_3 .

3.2 Finite size e ect of the GPDOS

A very in portant form all advance of the AC transport theory is the correct characterization of electric current conservation. In principle this requirement is satis ed by the AC transport form alism used here[6] which dem ands $^{P} E = 0$. Hence we must have $^{P} dN = dE = ^{P} D$. Since both sides of this equation represent the total scattering DOS, thus the current conservation is obtained. In practical calculations, the left hand side of this equation is computed externally, using the scattering matrix which is calculated at the boundaries of the scattering volume. On the other hand the right side of this equation is calculated boally, using the scattering wavefunction inside the scattering volume. These two quantities becomes precisely equal when the scattering volume is very large[19]. For a nite scattering volume, correction terms should be added to the GPDOS, as shown in Ref. [24] for 1D systems, and in Ref. [13] for a 2D system. Without the corrections, numerical results for a 2D quantum wire showed a small but systematic deviation from the precise current conservation [12]. Such a deviation actually diverges at the edges of successive propagation subbands as shown in Ref. [13].

Since partial density of states play a vital role in the AC transport form alism used in this work, in this section we present a detailed analysis of the nite size e ect of the scattering volum e to the GPDOS.To this purpose we have exam ined a variety of system sizes L form any energies near the onset of the second transport subband. As a measure, we de ne a quantity which is the di erence of the total DOS as calculated from GPDOS and LPDOS:

$$\frac{dN}{dE} \quad D \quad : \tag{11}$$

Obviously = 0 if the current is precisely conserved.

Fig. (5a) shows $_1$ as a function of the system size L for three energies very close to the second subband edge which is located at $E_2 = 39:4784$. A clear crossover to the large volum e lim it is revealed as $_1$! 0 when L is increased. It is also clear that for energy closer to E_2 , the crossover is slower (solid line). We found that the decay of $_1$ is essentially exponential for all energies exam ined, and has a interesting form for large L:

$$_{1}$$
 e $^{k_{2}(2L+1)}$ (12)

where (2L + 1) is precisely the scattering volum e length from probe I to probe II, and k_2 is the momentum corresponding to the second subband energy E_2 . We have plotted $\ln [1 = (2L + 1)] = k_2$ in Fig. (5b) for several energies. Our numerical data supports Eq. (12) quite well for large L, and for energies closer to E_2 . It is not di cult to understand the form of Eq. (12). Due to the scattering at the junction where the three probes meet, complicated mode mixing takes place. While the incoming electron is in the rst subband, modemixing generates wavefunctions for many higher subbands, including the second subband, which become evanescent in the probes. For a scattering volum e with a small L, the evanescent mode may \leak" out of the volum e. How ever when we calculate the GPDOS from the scattering matrix, these \leaked" evanescent modes are not explicitly included, leading to a nite . A swe increase L, the evanescent modes decays away, and is reduced. In a speci c example which can be solved exactly [13], a similar form to Eq.(12) was derived which was needed to correct the GPDOS in order to satisfy the precise current conservation. Our num erical study presented here reinforces the results of R ef. [13].

To further investigate the nite size e ect to GPDOS, in Fig. (6a,b) we plot the total DOS as obtained by GPDOS and LPDOS as functions of energy, for three system sizes L. The current conservation condition is satis ed very well for most of the rst subband energies. W hen approaching the end of rst subband, the current conservation condition is violated gradually, i.e. € 0. Wesee that for the sm allest scattering region L = 0, the agreem ent of the two total DOS is at best reasonable when the incident electron is from probe I and is away from the second subband edge (Fig. (6a)), and is quite bad when the electron is com ing from probe III (Fig. (6b)). The situation improves considerablely when we increased the system size. As shown in Fig. (6), for L = 1 and L = 2, the agreem ent of the two total DOS are much better. However there is always a divergent behavior near the second subband for all sizes exam ined if the energy is made very close enough to E_2 . Hence the e ect of increasing the size of the scattering volume is to decrease the \critical region" where the two total DOS disagrees.

4 Summary

In conclusion, the low frequency quantum transport properties of a three-probe m esoscopic conductor are studied using Buttiker's current conservation form alism. The static transm ission coe cients and em ittance m atrix of the system with di erent electric potentials are computed. We found that the behavior of the em ittance m atrix is closely related to that of the transm ission coe cients. We exam ined the nite size e ect of the GPDOS which a ects the electric current conservation. In general as the incom ing electron energy E approaching the threshold of the second subband, the nite-size GPDOS diverges and the current conservation is violated. The e ect of increasing the size of the scattering volum e is to decrease the region where the current conservation is violated.

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Figure Captions

- Figure 1. Schem atic plot of the 3-probe quantum wire system. The scattering volum e is de ned by the dotted lines.
- Figure 2. The transmission coe cients and the emittance E as functions of the incoming electron energy without the tunneling barriers. (a). Solid line: relection coe cient R $_{11}$; dotted line: transmission coe cient T $_{21}$; dashed line: T $_{31}$. (b). Emittance E . Solid line: E $_{11}$; dotted line: E $_{21}$; dashed line: E $_{31}$.
- Figure 3. Electron dwell time $_1$ as a function of the incoming electron energy in the tunneling regime. The three peaks indicate three resonance states in the system in this energy range. Inset: $_3$.
- Figure 4. The transmission coe cients and the emittance E as functions of the incoming electron energy in the tunneling regime. (a). Solid line: R_{11} ; dotted line: E_{11} ; (b). Solid line: T_{21} ; dotted line: E_{21} ; (c). Solid line: T_{31} ; dotted line: E_{31} .
- Figure 5. (a). The di erence, 1, of the total PDOS as computed from the GPDOS and LPDOS from Eq. (11) as a function of the scattering volum e linear size L. Solid line: at energy E = 39:46699; dotted line: at energy E = 39:45371; dashed line: at energy E = 39:44137; (b). The quantity, $\ln [1=(2L+1)]=k_2$ as a function of the linear size L for several incoming electron energies as shown. At large L, this quantity approaches unity, con ming the form of Eq. (12).
- Figure 6. Comparison of the totalPDOS computed from the GPDOS and LPDOS, as a function of the incom ing electron energy for three di erent sizes L = 0;1, and 2 in the transmissive regime. (a). Electrons com ing from probe 1. (b). Electrons com ing from probe 3. The agreem ent of the totalPDOS is quite good up to the \critical region" near the onset of the second subband.

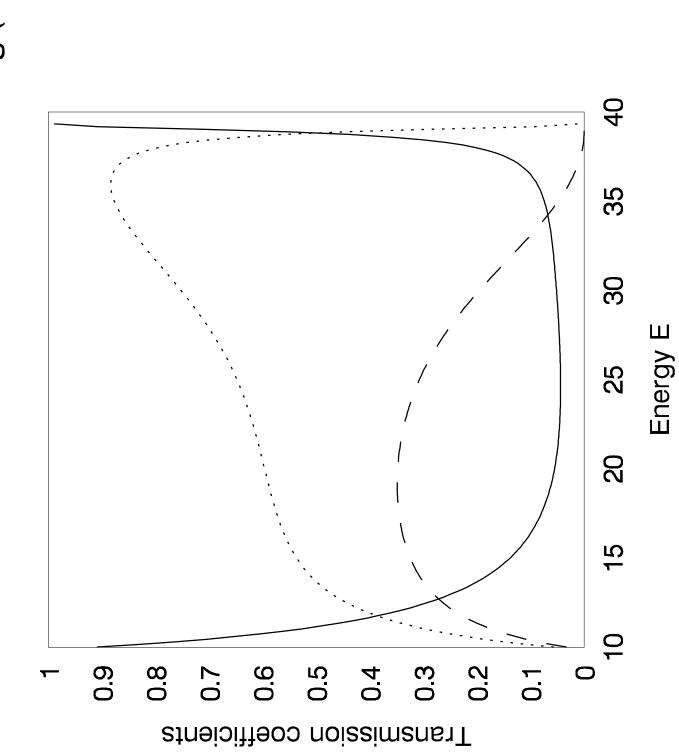


Fig.(2a)

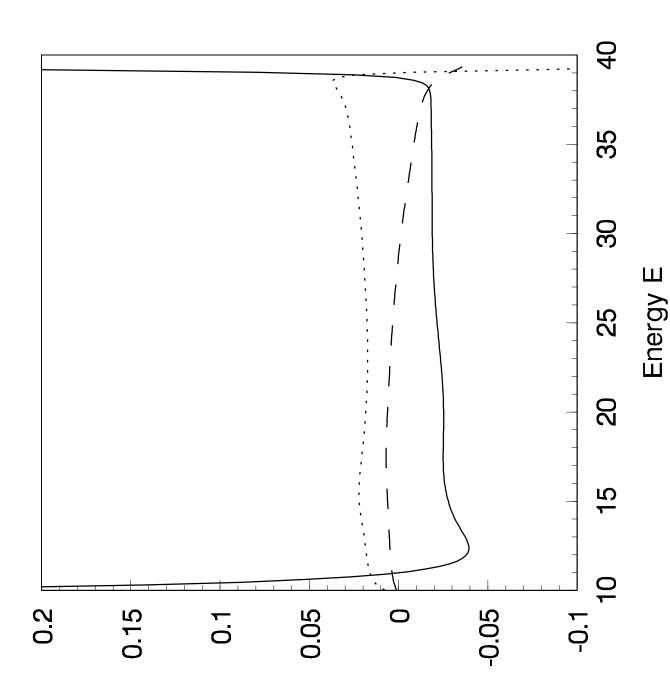
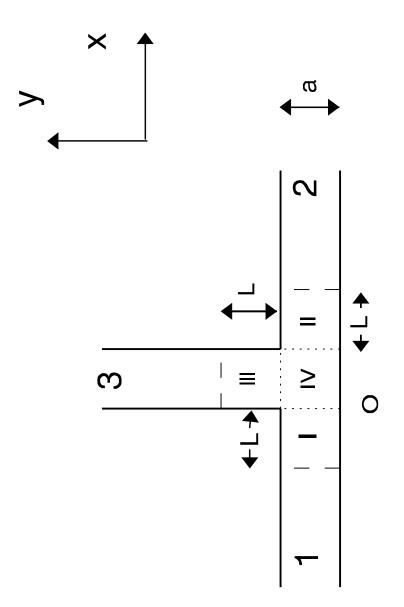


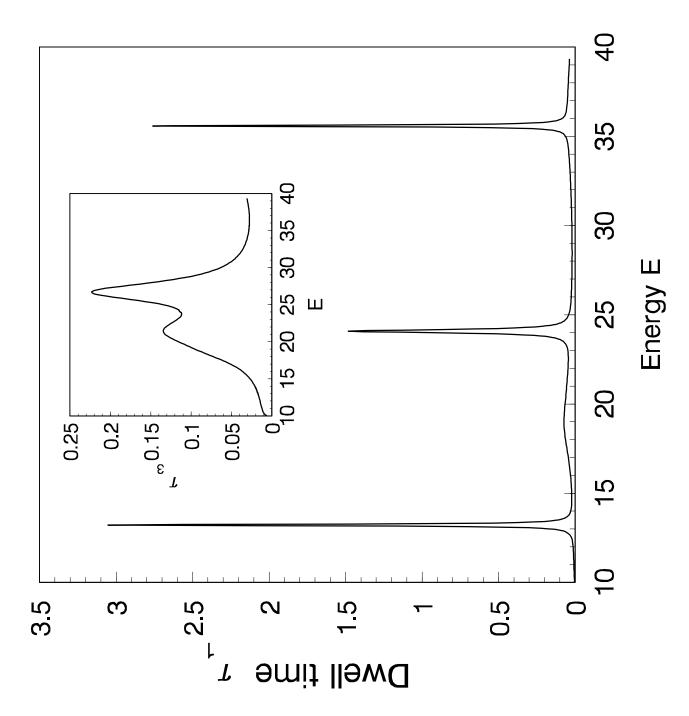
Fig.(2b)

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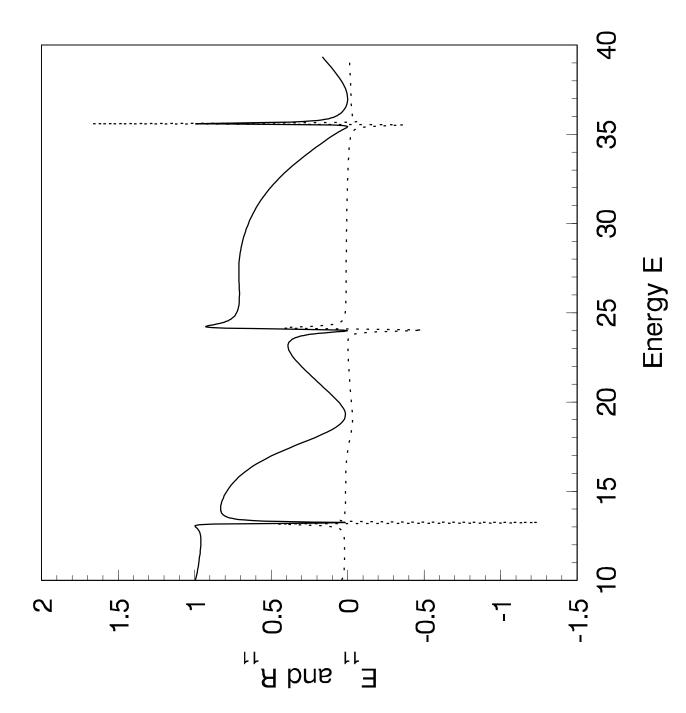


Figure(1)

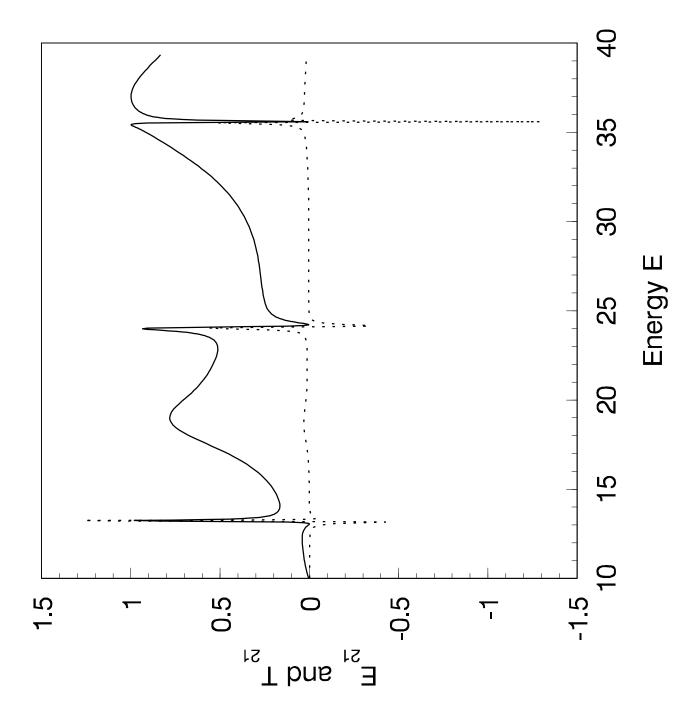


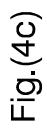












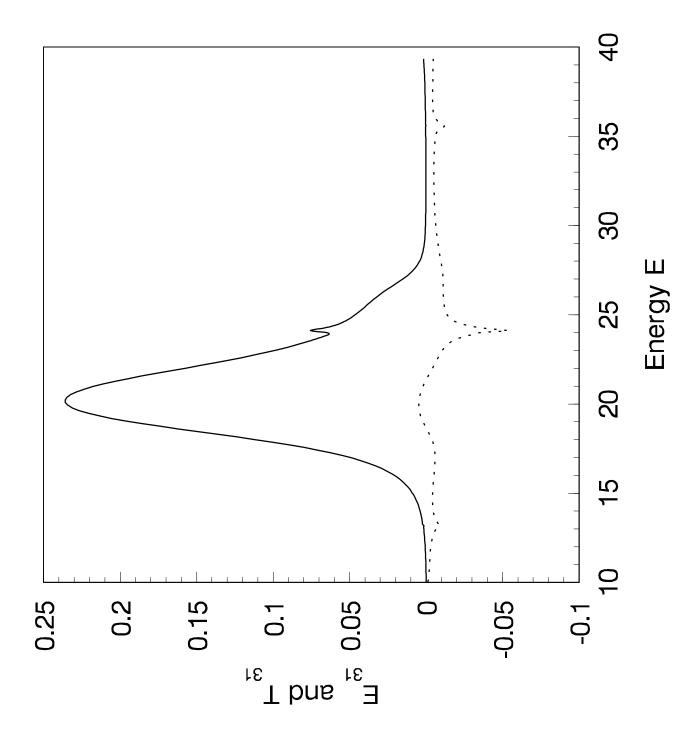
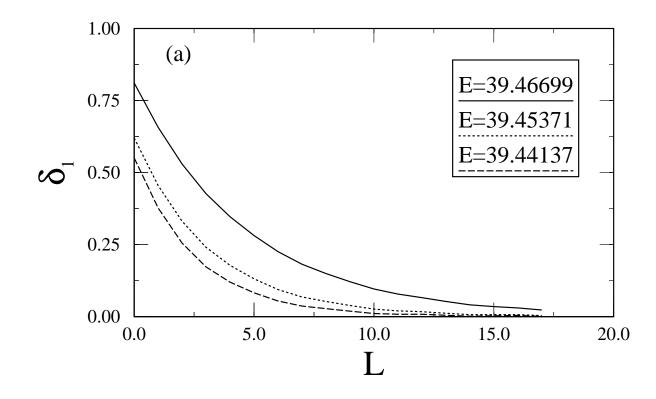


figure (5a)



TempleGraph 2.4, Origin: /morgoth/users/guo@celeborn - Tue Jan 21 10:26:58 1997 (data file was fig5a.dat)

figure (5b)

